

**DESCRIPTION**

The RTC56151 is a symmetric, single-pole four-throw (SP4T) antenna switch module (ASM). All inputs and outputs are internally matched to 50Ω and the DC block capacitors at antenna and each RF ports are not necessary. This feature reduces the parts count, shrinks the circuit size, widens the operating bandwidth, and cuts down the manufacturing costs. Low-loss, high power and high linearity make the SP4T ASM suitable for multimode and multiband applications such as GSM/WCDMA/EDGE. A decoder with low current consumption is included in the device, which uses only two DC voltages to control switch operations. At each RF port to the antenna-path, the typical insertion loss is 0.7 dB from 0.5 to 2.5 GHz. The isolation between each RF port is higher than 20 dB. The device can be operated at 1.8 to 3V wide supply range. These characteristics make RTC56151 SP4T ASM very useful in various applications, such as hand-held device and battery-powered equipment.

The RTC56151 is packaged in a very compact industry-standard 16-lead surface mount package QFN 3mm X 3 mm with lead-free RoHS compliant.

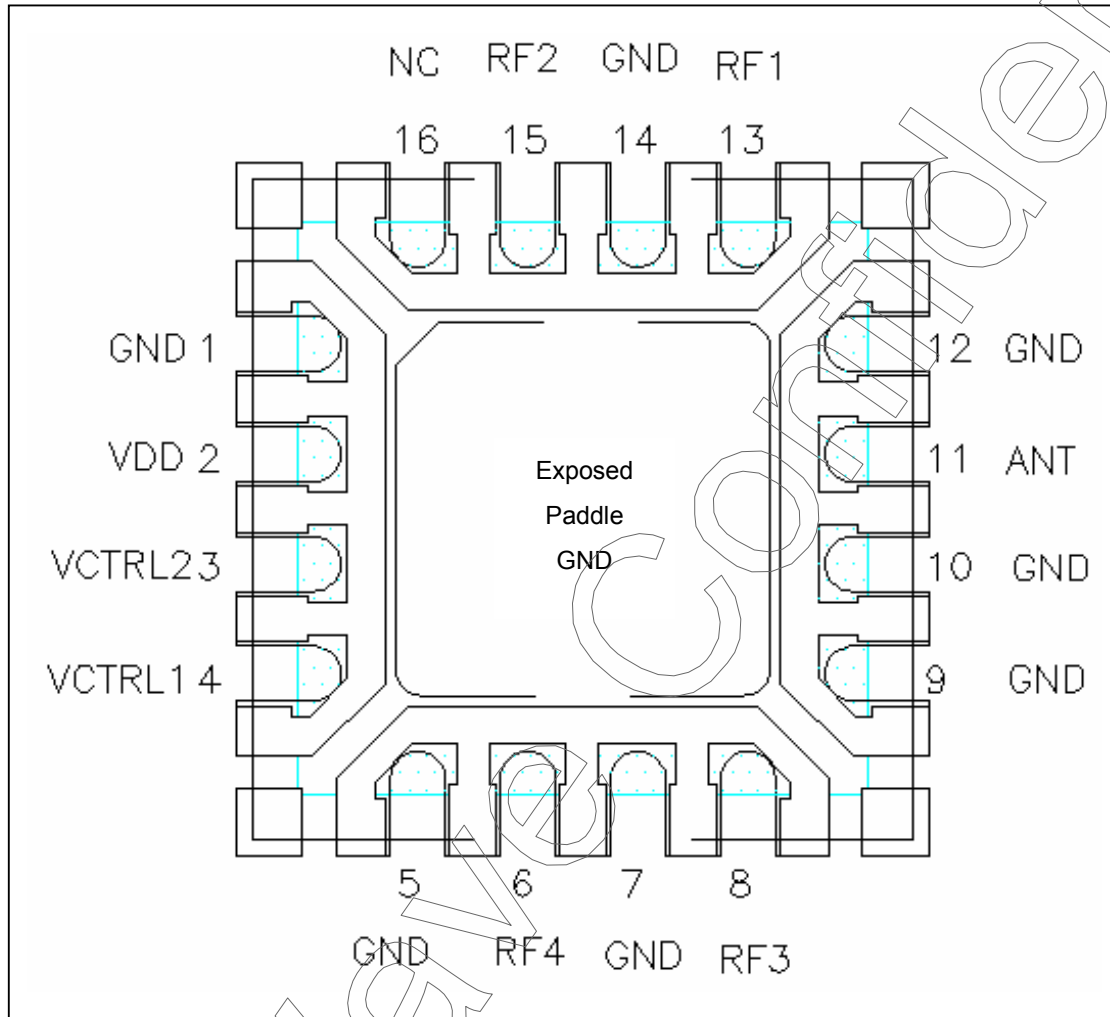
**FEATURE**

- ◆ Broadband frequency range (0.5-2.5GHz)
- ◆ Low insertion loss(0.4dB@1GHz, 0.5dB@2GHz) & high isolation(28.5dB@1GHz)
- ◆ Wide supply range  $V_{DD}=1.8$  to 3 V
- ◆ High linearity IMD3 < -105dBm
- ◆ Good spurious harmonic performance -70dBc @900MHz, +34.5dBm input power
- ◆ Low logic control voltage  $V_{CTRL}$  down to 1.8V
- ◆ 16L QFN3 X 3 X 0.75 mm package
- ◆ Lead(Pb) free, RoHS compliant

**APPLICATION**

- ◆ Mobile Handset System Application
- ◆ Data Card Application
- ◆ Multi-Mode GSM/GPRS/WCDMA Application

**PIN OUT** (top view)



**PIN FUNCTION DESCRIPTION**

Pin	Function	Description
1,5,7,9,10,12,14	GND	Ground connection
2	V <sub>DD</sub>	Supply voltage for switch operation
3	V <sub>CTRL2</sub>	Control voltage 2.
4	V <sub>CTRL1</sub>	Control voltage 1
6	RF4	RF output 4
8	RF3	RF output 3
11	ANT	Antenna port
13	RF1	RF output 1
15	RF2	RF output 2
16	NC	No connection

## ABSOLUTE MAXIMUM RATINGS

Parameter	Rating	Units
Supply Voltage ( $V_{DD}$ )	5	V
TX Input Power	36	dBm
Control Voltage ( $V_{CTRL}$ )	5	V
Operating Temperature	-30 to +85	°C
Storage Temperature	-50 to +100	°C

Note : Exceeding these ranges might cause damage to the device

## LOGIC TABLE

State	$V_{CTRL1}$	$V_{CTRL2}$	RF Path
1	0	0	ANT to RF1
2	0	1	ANT to RF2
3	1	0	ANT to RF3
4	1	1	ANT to RF4

"1" = +1.8V to + $V_{DD}$  "0" = 0V to +0.3V

## DC/CONTROL SPECIFICATIONS

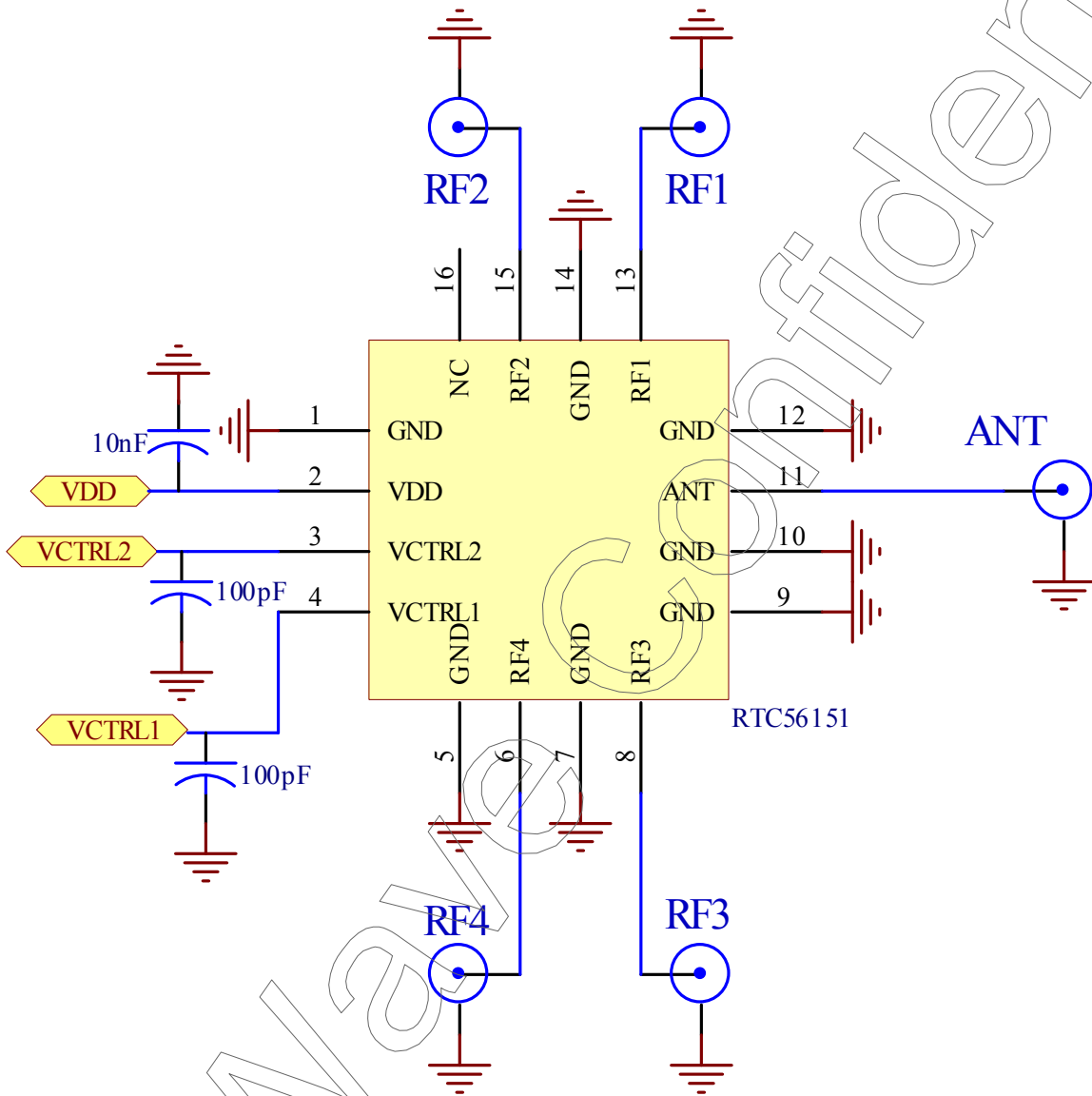
State	Conditions	Min	Typ	Max	Unit
Switched supply voltage( $V_{DD}$ )		1.8		3	V
Switched supply current( $I_{DD}$ )			0.3		mA
Control voltage	$V_{HIGH}$	1.8	2.65	3	V
	$V_{LOW}$		0	0.3	V
Control current	$I_{HIGH}$		0.1		$\mu A$
	$I_{LOW}$		0.1		$\mu A$

## AC ELECTRICAL CHARACTERISTICS

$T_A = 25^\circ\text{C}$ ,  $V_{DD} = 2.65\text{ V}$ ,  $V_{CTRL1} = V_{CTRL2} = V_{DD}$ , all unused RF ports are terminated in a  $50\ \Omega$  load, unless otherwise noted

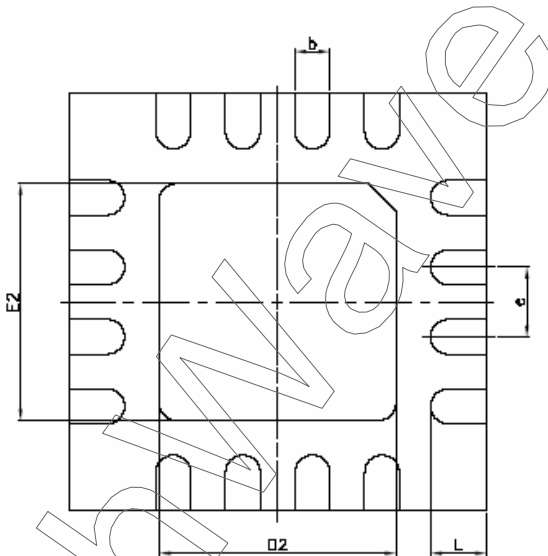
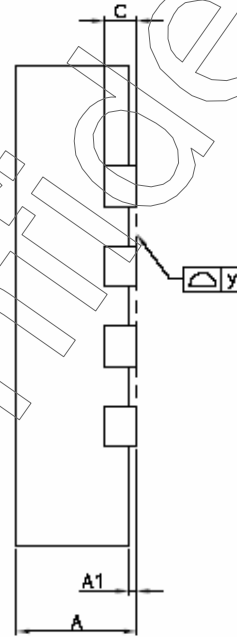
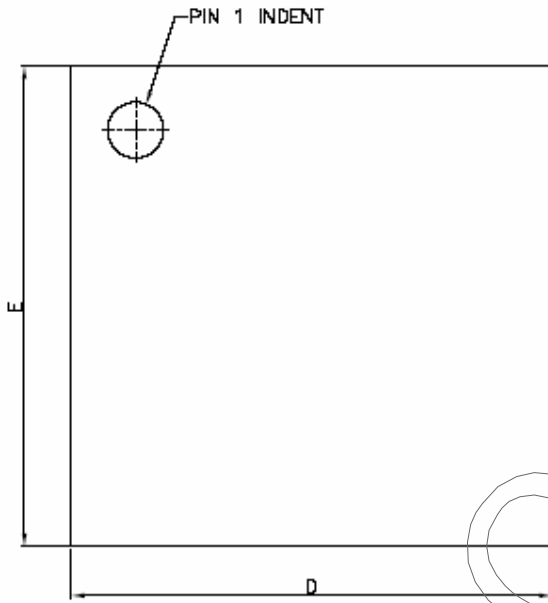
Parameter	Conditions	Min	Typ	Max	Unit
Insertion loss	0.5 to 1.0 GHz		0.40		dB
	1.0 to 2.0 GHz		0.50		dB
	2.0 to 2.1 GHz		0.50		dB
	2.5 GHz		0.7		dB
Isolation	0.5 to 1.0 GHz		28.5		dB
	1.0 to 2.0 GHz		22.0		dB
	2.0 to 2.1 GHz		21.5		dB
	2.5 GHz		19.0		dB
Return loss	0.50 to 2.5 GHz, all RF ports, insertion loss state		20		dB
Second harmonic( $2f_0$ )	Fundamental Frequency 900 MHz, $P_{IN} = +34.5\text{ dBm}$		-75		dBc
	Fundamental Frequency 1.8 GHz, $P_{IN} = +31.5\text{ dBm}$		-70		dBc
Third harmonic( $3f_0$ )	Fundamental Frequency 900 MHz, $P_{IN} = +34.5\text{ dBm}$		-70		dBc
	Fundamental Frequency 1.8 GHz, $P_{IN} = +31.5\text{ dBm}$		-70		dBc
Input 0.1 dB compression point( $P_{0.1\text{dB}}$ )	@ 900 MHz		35		dBm
	@ 1.8 GHz		35		dBm
3rd Order Intermodulation Distortion(IMD3)	$f_{\text{FUND}} = 1.95\text{ GHz @ } +20\text{ dBm}$ , $f_{\text{BLK}} = 1.76\text{ GHz @ } -15\text{ dBm}$ , $f_{\text{RX}} = 2.14\text{ GHz}$ , worst case over phase.		-105		dBm
Power handling under mismatch	@ 900 MHz, VSWR = 20:1		34.5		dBm
	@ 1.8 GHz, VSWR = 20:1		31.5		dBm
2nd Order Input Intercept Point	$f_0 = 836.61\text{ MHz @ } +26\text{ dBm}$ , $f_2 = 1718.22\text{ MHz @ } -20\text{ dBm}$ , measured @ 881.61 MHz		110		dBm
Switching speed	10%/90% RF rise/fall time		0.27		$\mu\text{s}$
Startup time	Wait time required when $V_{DD}$ is applied until control voltage can be applied		25		$\mu\text{s}$

APPLICATION CIRCUIT :



**PACKAGE DRAWING**

**16L QFN-3mm X 3mm X 0.75mm**



SYMBOLS	DIMENSIONS IN MILLIMETERS		
	MIN	NOM	MAX
A	0.70	0.75	0.80
A1	0.00	0.02	0.05
b	0.18	0.25	0.30
C	—	0.20 REF.	—
D	2.90	3.00	3.10
D2	1.65	1.70	1.75
E	2.90	3.00	3.10
E2	1.65	1.70	1.75
e	—	0.50	—
L	0.35	0.40	0.45
y	0.00	—	0.075